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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

More Patent Application of)
ELIYAHOU HARARI, ROBERT D.)
NORMAN and SANJAY MEHROTRA)
Serial No.: UNASSIGNED)
Filed: HEREWITH)
For: FLASH Eeprom SYSTEM)

Group Art Unit: 2413

San Francisco, California

Hon. Commissioner of
Patents and Trademarks
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

Please amend the accompanying continuation application,
concurrently with its filing, as follows:

IN THE SPECIFICATION:

Page 1, between lines 3 and 4, insert the following:

--Cross-Reference to Related Applications

This is a continuation of patent application serial no.
08/174,768, filed December 29, 1993, now patent no. 5,602,987
which in turn is a continuation of patent application serial no.
07/963,838, filed October 20, 1992, now patent no. 5,297,148, which
in turn is a division of patent application serial no. 07/337,566,
filed April 13, 1989, now abandoned.--

Page 4, between lines 27 and 28, insert the following:

--The present invention also includes improvements in
EEprom array read and write circuits and techniques in order to
provide multiple threshold levels that allow accurate reading and
writing of more than two distinct states within each memory cell
over an extended lifetime of the memory cells, so that more than
one bit may be reliably stored in each cell.

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